Product data sheet

1. General description

NPN medium power transistors in a SOT89 (SC-62) flat lead Surface-Mounted Device (SMD) plastic package

2. Features and benefits

- High collector current capability I_C and I_{CM}
- Three current gain selections
- · High power dissipation capability
- AEC-Q101 qualified

3. Applications

- Linear voltage regulators
- MOSFET drivers
- · Low-side switches
- · Battery-driven devices
- · Power management
- MOSFET drivers
- Amplifiers

4. Quick reference data

Table 1. Quick reference data

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base		-	-	80	V
Ic	collector current			-	-	1	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	2	А
h _{FE}	h _{FE} DC current gain						
	BCX56	V _{CE} = 2 V; I _C = 150 mA	[1]	63	-	250	
	BCX56-10		[1]	63	-	160	
	BCX56-16		[1]	100	-	250	

[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$



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5. Pinning information

Table 2. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	Е	emitter		C
2	С	collector		в
3	В	base		13
			3 2 1	sym042

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BCX56	SC-62	plastic, surface-mounted package with increased heatsink; 4	SOT89			
BCX56-10		leads				
BCX56-16						

7. Marking

Table 4. Marking

Type number	Marking code							
BCX56	ВН							
BCX56-10	ВК							
BCX56-16	BL							

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8. Limiting values

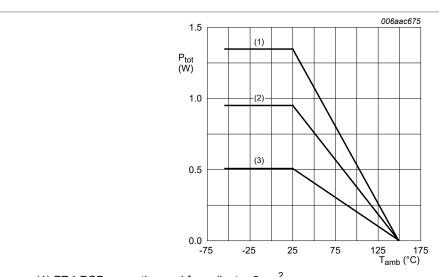
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	open emitter		100	V
V _{CEO}	collector-emitter voltage	open base		-	80	V
V _{EBO}	emitter-base voltage	open collector		-	5	V
I _C	collector current			-	1	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	single pulse; t _p ≤ 1 ms		2	Α
I _B	base current			-	0.3	Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms	single pulse; t _p ≤ 1 ms		0.3	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	0.50	W
			[2]	-	0.95	W
			[3]	-	1.35	W
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

- Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm². Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 6 cm².



- (1) FR4 PCB, mounting pad for collector 6 cm²
- (2) FR4 PCB, mounting pad for collector 1 cm²
- (3) FR4 PCB, standard footprint

Fig. 1. Power derating curves SOT89

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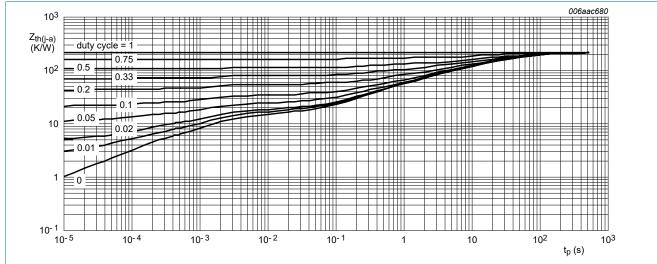
9. Thermal characteristics

Table 6. Thermal characteristics

 T_{amb} = 25 °C unless otherwise specified.

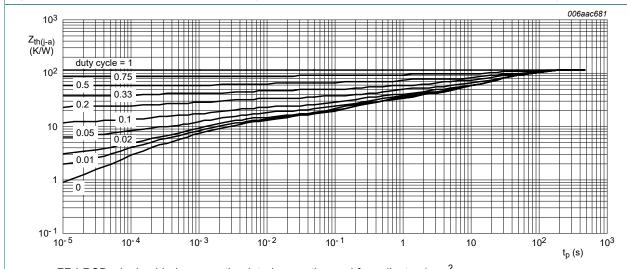
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	250	K/W
			[2]			132	K/W
			[3]			93	K/W
R _(j-sp)	thermal resistance from junction to solder point			-	-	16	K/W

- [1] Device mounted on an FR4 PCB; single-sided copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm².
- Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 6 cm².



FR4 PCB; single-sided copper; tin-plated and standard footprint

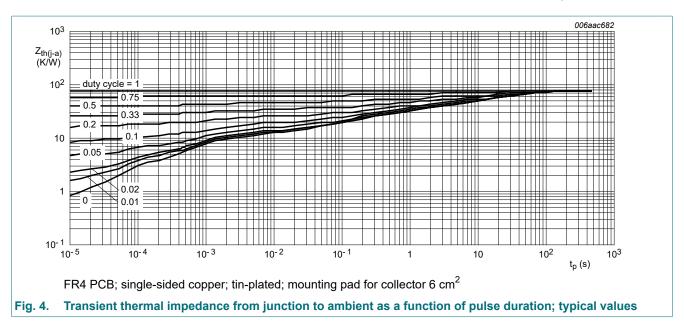
Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm²

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

Table 7. Characteristics

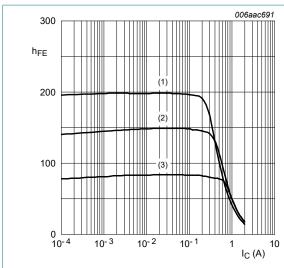
 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	I _C = 100 μA; I _E = 0 A		100	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = 2 mA; I _B = 0 A		80	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	I _E = 100 μA; I _C = 0 A		5	-	-	V
I _{CBO}	collector-base	V _{CB} = 30 V; I _E = 0 A		-	-	100	nA
	cut-off current	$V_{CB} = 30 \text{ V}; I_{E} = 0 \text{ A}; T_{j} = 150 \text{ °C}$		-	-	10	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A		-	-	100	nA
h _{FE}	DC current gain		'		'	'	
	BCX56	V _{CE} = 2 V; I _C = 5 mA	[1]	63	-	-	
		V _{CE} = 2 V; I _C = 150 mA		63	-	250	
		V _{CE} = 2 V; I _C = 500 mA		40	-	-	
	BCX56-10	V _{CE} = 2 V; I _C = 5 mA	[1]	63	-	-	
		V _{CE} = 2 V; I _C = 150 mA		63	-	160	
		V _{CE} = 2 V; I _C = 500 mA		40	-	-	
	BCX56-16	V _{CE} = 2 V; I _C = 5 mA	[1]	63	-	-	
		V _{CE} = 2 V; I _C = 150 mA		100	-	250	
		V _{CE} = 2 V; I _C = 500 mA		40	-	-	
V _{CEsat}	collector-emitter saturation voltage	I _C = 500 mA; I _B = 50 mA	[1]	-	-	0.5	V
V_{BE}	base-emitter voltage	V _{CE} = 2 V; I _C = 500 mA	[1]	-	-	1	V
C _c	collector capacitance	V _{CB} = 10 V; I _E = i _e = 0 A; f = 1 MHz		-	6	-	pF
f _T	transition frequency	V _{CE} = 5 V; I _C = 50 mA; f = 100 MHz		100	180	-	MHz

^[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$

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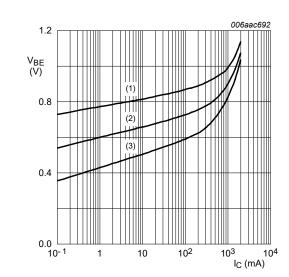
$$V_{CE} = 2 V$$

(1)
$$T_{amb}$$
 = 100 °C

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55$$
 °C

Fig. 5. DC current gain as a function of collector current; typical values



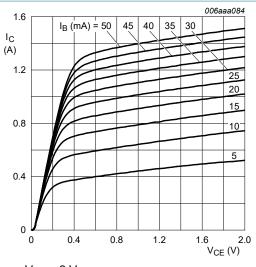
$$V_{CE} = 2 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 7. Base-emitter voltage as a function of collector current; typical values



$$V_{CE} = 2 V$$

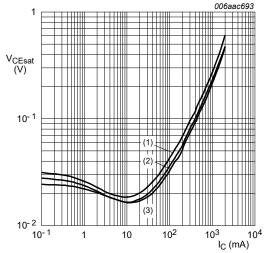
(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 6. Collector current as a function of collectoremitter voltage; typical values





$$I_C/I_B = 10$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 9.

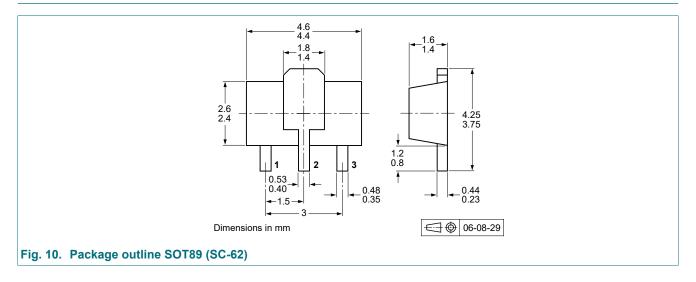
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11. Test information

11.1. Quality information

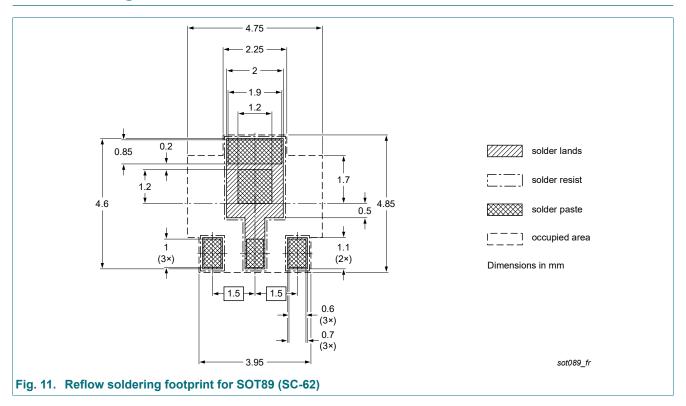
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

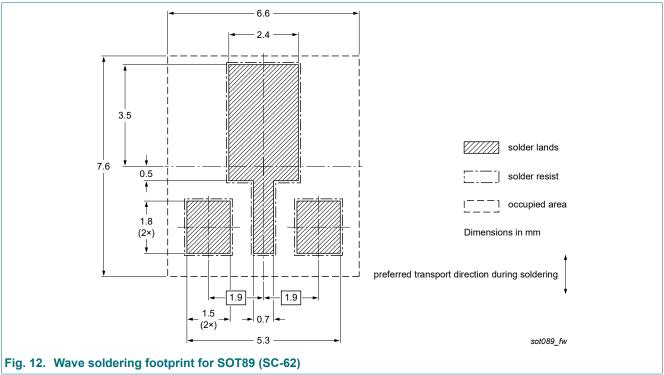
12. Package outline



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13. Soldering





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14. Revision history

Table 8. Revision history

Table 6. Revision history								
Document ID	Release date	Data sheet status	Change notice	Supersedes				
BCX56_SER v.10	20220624	Product data sheet	-	BCP56_BCX56_BC56PA v.9				
Modifications:	Family data she package.Packing information	et describing several pacation removed.	ckages reduced to	o series data sheets per				
BCP56_BCX56_BC56PA v.9	20111025	Product data sheet	-	BC639_BCP56_BCX56 v.8				
BC639_BCP56_BCX56 v.8	20070622	Product data sheet	-	BC639_BCP56_BCX56 v.7				
BC639_BCP56_BCX56 v.7	20050308	Product data sheet		BC639_BCP56_BCX56 v.6				
BC639_BCP56_BCX56 v.6	20050303	Product data sheet	CPCN2004050 29	BC635_637_639 v.4 BCP54_55_56 v.5 BCX54_55_56 v.4				
BC635_637_639 v.4	20011010	Product specification	-	BC635_637_639 v.3				
BCX54_55_56 v.5	20030206	Product specification	-	BCX54_55_56 v.4				
BCX54_55_56 v.4	20011010	Product specification	-	BCX54_55_56 v.3				

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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